## FEATURES

$5 \Omega$ max on resistance
$0.5 \Omega$ max on resistance flatness
33 V supply maximum ratings
Fully specified at $\pm 15 \mathrm{~V} / 12 \mathrm{~V} / \pm 5 \mathrm{~V}$
3 V logic compatible inputs
Rail-to-rail operation
Break-before-make switching action
16-lead TSSOP and $4 \mathrm{~mm} \times 4 \mathrm{~mm}$ LFCSP packages
Typical power consumption (<0.03 $\mu \mathrm{W}$ )

## APPLICATIONS

## Relay replacement

Audio and video routing
Automatic test equipment
Data acquisition systems
Battery-powered systems
Sample-and-hold systems
Communication systems
Relay replacement

## GENERAL DESCRIPTION

The ADG1408 and ADG1409 are monolithic iCMOS analog multiplexers comprising eight single channels and four differential channels, respectively. The ADG1408 switches one of eight inputs to a common output as determined by the 3-bit binary address lines A0, A1, and A2. The ADG1409 switches one of four differential inputs to a common differential output as determined by the 2-bit binary address lines A0 and A1. An EN input on both devices is used to enable or disable the device. When disabled, all channels are switched OFF.

The $i$ CMOS (industrial-CMOS) modular manufacturing process combines high-voltage CMOS (complementary metaloxide semiconductor) and bipolar technologies. It enables the development of a wide range of high performance analog ICs capable of $30-\mathrm{V}$ operation in a footprint that no other generation of high-voltage parts has been able to achieve. Unlike analog ICs using conventional CMOS processes, $i$ CMOS components can tolerate high supply voltages, while providing increased performance, dramatically lower power consumption, and reduced package size.

## FUNCTIONAL BLOCK DIAGRAMS



Figure 1.

The ultralow on resistance and on resistance flatness of these switches make them ideal solutions for data acquisition and gain switching applications, where low distortion is critical. $i$ CMOS construction ensures ultralow power dissipation, making the parts ideally suited for portable and battery powered instruments

## PRODUCT HIGHLIGHTS

1. $5 \Omega$ max on resistance.
2. $0.5 \Omega$ max on resistance flatness.
3. 3 V logic compatible digital input $\mathrm{V}_{\mathrm{IH}}=2.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{IL}}=0.8 \mathrm{~V}$.
4. 16-lead TSSOP and $4 \mathrm{~mm} \times 4 \mathrm{~mm}$ LFCSP package.

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## SPECIFICATIONS

## DUAL SUPPLY ${ }^{1}$

$\mathrm{V}_{\mathrm{DD}}=+15 \mathrm{~V} \pm 10 \%, \mathrm{~V}_{\mathrm{SS}}=-15 \mathrm{~V} \pm 10 \%$, GND $=0 \mathrm{~V}$, unless otherwise noted.
Table 1.


| Parameter | $+25^{\circ} \mathrm{C}$ | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | Unit | Test Conditions/Comments |
| :---: | :---: | :---: | :---: | :---: | :---: |
| DYNAMIC CHARACTERISTICS² |  |  |  |  |  |
| ADG1408 | 100 |  |  | pF typ |  |
| ADG1409 | 50 |  |  | pF typ |  |
| $\mathrm{C}_{\mathrm{D}}, \mathrm{C}_{5}(\mathrm{ON})$ |  |  |  |  | $\mathrm{f}=1 \mathrm{MHz}$ |
| ADG1408 | 150 |  |  | pF typ |  |
| ADG1409 | 75 |  |  | pF typ |  |
| POWER REQUIREMENTS ID | 0.001 | 5 | 5 | $\mu \mathrm{A}$ typ $\mu \mathrm{A}$ max | $\mathrm{V}_{\mathrm{DD}}=+16.5 \mathrm{~V}, \mathrm{~V}_{\text {SS }}=-16.5 \mathrm{~V}$ |
|  |  |  |  |  | Digital inputs $=0 \mathrm{~V}$ or $\mathrm{V}_{\mathrm{DD}}$ |
|  |  |  |  |  |  |
| IDD | 150 |  |  | $\mu \mathrm{A}$ typ | Digital inputs $=5 \mathrm{~V}$ |
|  |  |  | 300 | $\mu \mathrm{A}$ max |  |
| Iss | 0.001 |  |  | $\mu \mathrm{A}$ typ | Digital inputs $=0 \mathrm{~V}$ or $\mathrm{V}_{\mathrm{DD}}$ |
|  |  | 5 | 5 | $\mu \mathrm{A}$ max |  |
| IGnd | 0.001 |  |  | $\mu \mathrm{A}$ typ | Digital inputs $=0 \mathrm{~V}$ or $\mathrm{V}_{\mathrm{DD}}$ |
|  |  | 5 | 5 | $\mu \mathrm{A}$ max |  |
| Ignd | 150 |  |  | $\mu \mathrm{A}$ typ | Digital inputs $=5 \mathrm{~V}$ |
|  |  | 5 | 300 | $\mu \mathrm{A}$ max |  |

${ }^{1}$ Temperature ranges are as follows: B Version: $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$; T Version: $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$.
${ }^{2}$ Guaranteed by design, not subject to production test.

## SINGLE SUPPLY ${ }^{1}$

$\mathrm{V}_{\mathrm{DD}}=12 \mathrm{~V} \mathrm{~V} \pm 10 \%$,, $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}, \mathrm{GND}=0 \mathrm{~V}$, unless otherwise noted.
Table 2.

| Parameter | $+25^{\circ} \mathrm{C}$ | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | Unit | Test Conditions/Comments |
| :---: | :---: | :---: | :---: | :---: | :---: |
| ANALOG SWITCH |  |  |  |  |  |
| Analog Signal Range |  |  | 0 to $V_{\text {D }}$ | V |  |
| Ron | 6 |  |  | $\Omega$ typ | $\mathrm{V}_{\mathrm{D}}=3 \mathrm{~V}, 10 \mathrm{~V}, \mathrm{I}_{\mathrm{s}}=-1 \mathrm{~mA}$ |
|  | 7 | 8 | 9 | $\Omega$ max |  |
| Ron Flatness |  |  |  | $\Omega$ typ | $\mathrm{V}_{\mathrm{D}}=3 \mathrm{~V}, 10 \mathrm{~V}, \mathrm{I}_{\mathrm{s}}=-1 \mathrm{~mA}$ |
|  | 1.5 |  |  | $\Omega$ max |  |
| $\triangle$ Ron | 0.5 |  |  | $\Omega$ typ | $\mathrm{V}_{\mathrm{D}}=3 \mathrm{~V}, 10 \mathrm{~V}, \mathrm{I}_{\mathrm{s}}=-1 \mathrm{~mA}$ |
|  |  |  |  | $\Omega$ max |  |
| Channel ON Leakage $\mathrm{I}_{\mathrm{D}}, \mathrm{I}_{\mathrm{s}}(\mathrm{ON})$ ADG1408 |  |  |  |  | $\mathrm{V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{D}}=8 \mathrm{~V} / 0 \mathrm{~V} ;$ |
|  | $\pm 1$ | $\pm 100$ | $\pm 100$ | nA max | Test Circuit 4 |
| ADG1409 | $\pm 1$ | $\pm 50$ | $\pm 50$ | nA max |  |
| DIGITAL INPUTS |  |  |  |  |  |
| Input High Voltage, $\mathrm{V}_{\text {INH }}$ |  | 2.0 | 2.0 | $\checkmark$ min |  |
| Input Low Voltage, VINL |  | 0.8 | 0.8 | $V$ max |  |
| Input Current |  |  |  |  |  |
| linL or linh | 8 | $\pm 10$ | $\pm 10$ | $\mu \mathrm{A}$ max | $\mathrm{V}_{\mathrm{IN}}=0$ or $\mathrm{V}_{\mathrm{DD}}$ |
| $\mathrm{C}_{1 \times}$, Digital Input Capacitance |  |  |  | pF typ | $\mathrm{f}=1 \mathrm{MHz}$ |
| DYNAMIC CHARACTERISTICS² |  |  |  |  |  |
| $t_{\text {transition }}$ | 130 |  |  | ns typ | $\mathrm{R}_{\mathrm{L}}=300 \Omega, \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF}$; |
|  |  |  |  |  | $\mathrm{V}_{51}=8 \mathrm{~V} / 0 \mathrm{~V}, \mathrm{~V}_{58}=0 \mathrm{~V} / 8 \mathrm{~V}$; |
|  |  |  |  |  | Test Circuit 5 |
| $\mathrm{T}_{\text {Bвм }}$ | 10 |  |  | ns typ | $\mathrm{R}_{\mathrm{L}}=300 \Omega, \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF}$; |
|  |  |  | 1 | ns min | $\mathrm{V}_{\mathrm{s}}=5 \mathrm{~V}$; Test Circuit 6 |
| ton (EN) | 140 |  |  | ns typ | $\mathrm{RL}_{\mathrm{L}}=300 \Omega \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF}$; |
|  |  |  |  |  | $\mathrm{V}_{\mathrm{s}}=5 \mathrm{~V}$; Test Circuit 7 |


${ }^{1}$ Temperature ranges are as follows: B Version: $-40^{\circ} \mathrm{C}$ to $+85^{\circ}$; TVersion: $-55^{\circ} \mathrm{C}$ to $+125^{\circ}$.
${ }^{2}$ Guaranteed by design, not subject to production test.

## DUAL SUPPLY ${ }^{1}$

$\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V} \pm 10 \%, \mathrm{~V}_{\mathrm{SS}}=-5 \mathrm{~V} \pm 10 \%$, GND $=0 \mathrm{~V}$, unless otherwise noted.
Table 3.

| Parameter | $+25^{\circ} \mathrm{C}$ | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | Unit | Test Conditions/Comments |
| :---: | :---: | :---: | :---: | :---: | :---: |
| ANALOG SWITCH |  |  |  |  |  |
| Analog Signal Range |  |  | $V_{S S}$ to $V_{\text {DD }}$ | V |  |
| Ron | 6 |  |  | $\Omega$ typ | $\mathrm{V}_{\mathrm{D}}= \pm 3.3 \mathrm{~V}, \mathrm{I}_{\mathrm{s}}=-10 \mathrm{~mA}$ |
|  | 7 | 8 | 10 | $\Omega$ max |  |
| $\triangle$ Ron | 0.5 |  |  | $\Omega$ max | $\mathrm{V}_{\mathrm{D}}=+3.3 \mathrm{~V},-3.3 \mathrm{~V}$ |
| LEAKAGE CURRENTS |  |  |  |  |  |
| Source OFF Leakage Is (OFF) | $\pm 0.01$ |  |  | nA typ | $V_{D}= \pm 3.3 \mathrm{~V}, \mathrm{~V}_{\mathrm{S}}=-3.3 \mathrm{~V} ;$ <br> Test Circuit 2 |
|  | $\pm 0.5$ | $\pm 2.5$ | $\pm 50$ | $n A$ max |  |
| Drain OFF Leakage lo (OFF) |  |  |  |  | $\mathrm{V}_{\mathrm{D}}= \pm 3.3 \mathrm{~V} ; \mathrm{V}_{\mathrm{S}}= \pm 3.3 \mathrm{~V}$; |
| ADG1408 | $\pm 1$ | $\pm 100$ | $\pm 100$ | $n A$ max | Test Circuit 3 |
| ADG1409 | $\pm 1$ | $\pm 50$ | $\pm 50$ | $n A$ max |  |
| Channel ON Leakage $\left.\mathrm{I}_{\mathrm{D},} \mathrm{I} \mathrm{s}^{(O N}\right)$ |  |  |  |  | $\mathrm{V}_{\mathrm{s}}=\mathrm{V}_{\mathrm{D}}= \pm 3.3 \mathrm{~V}$; |
| ADG1408 | $\pm 1$ | $\pm 100$ | $\pm 100$ | $n A$ max | Test Circuit 4 |
| ADG1409 | $\pm 1$ | $\pm 50$ | $\pm 50$ | $n A$ max |  |



[^0]
## ABSOLUTE MAXIMUM RATINGS

Absolute maximum ratings $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, unless otherwise noted.
Table 4.

| Parameter | Rating |
| :---: | :---: |
| $\mathrm{V}_{\text {DD }}$ to $\mathrm{V}_{\text {SS }}$ | 36 V |
| VDo to GND | -0.3 V to +25 V |
| Vss to GND | +0.3 V to -25V |
| Analog, Digital Inputs ${ }^{1}$ | $V_{S S}-0.3 \mathrm{~V} \text { to } \mathrm{V}_{\mathrm{DD}}+0.3 \mathrm{~V}$ <br> or 20 mA , whichever occurs first |
| Continuous Current, S or D | 30 mA |
| Peak Current, S or D (Pulsed at 1 ms , 10\% Duty Cycle max) | 100 mA |
| Operating Temperature Range |  |
| Industrial (B Version) | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| Automotive (Y Version) | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| Storage Temperature Range | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Junction Temperature | $150^{\circ} \mathrm{C}$ |
| TSSOP Package, Power Dissipation | 450 mW |
| $\theta_{\mathrm{JA}}$, Thermal Impedance | $150.4^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\theta_{j c}$, Thermal Impedance | $50^{\circ} \mathrm{C} / \mathrm{W}$ |
| Lead Temperature, Soldering |  |
| Vapor Phase (60 sec) | $215^{\circ} \mathrm{C}$ |
| Infrared (15 sec) | $220^{\circ} \mathrm{C}$ |

${ }^{1}$ Overvoltages at A, EN, S, or D are clamped by internal diodes. Current should be limited to the maximum ratings given

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those listed in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Only one absolute maximum rating may be applied at any one time.

## ESD CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance

PIN CONFIGURATIONS


Figure 2. Pin Configurations-TSSOP

Table 6. ADG1409 Truth Table

| AI | AO | EN | ON SWITCH PAIR |
| :--- | :--- | :--- | :--- |
| $X$ | $X$ | 0 | NONE |
| 0 | 0 | 1 | 1 |
| 0 | 1 | 1 | 2 |
| 1 | 0 | 1 | 3 |
| 1 | 1 | 1 | 4 |

Figure 3. Pin Configurations $-4 m m \times 4 m m$ LFCSP

## TERMINOLOGY

Table 7.

| Mnemonic | Description |
| :---: | :---: |
| $V_{\text {DD }}$ | Most positive power supply potential. |
| Vss | Most negative power supply potential in dual supplies. In single supply applications, it may be connected to ground. |
| GND | Ground ( 0 V ) reference. |
| Ron | Ohmic resistance between D and S. |
| $\Delta$ Ron | Difference between the Ron of any two channels. |
| $\mathrm{I}_{5}$ (OFF) | Source leakage current when the switch is off. |
| ID (OFF) | Drain leakage current when the switch is off. |
| $\mathrm{ld}, \mathrm{ls}$ (ON) | Channel leakage current when the switch is on. |
| $V_{\text {d }}$ (vs) | Analog voltage on terminals D, S. |
| $\mathrm{C}_{s}$ (OFF) | Channel input capacitance for OFF condition. |
| $\mathrm{C}_{\mathrm{D}}$ (OFF) | Channel output capacitance for OFF condition. |
| $\mathrm{C}_{\mathrm{d}}, \mathrm{C}_{\mathrm{s}}(\mathrm{ON})$ | ON switch capacitance. |
| $\mathrm{Cl}_{\mathrm{N}}$ | Digital input capacitance. |
| ton (EN) | Delay time between the $50 \%$ and $90 \%$ points of the digital input and switch ON condition. |
| toff (EN) | Delay time between the $50 \%$ and $90 \%$ points of the digital input and switch OFF condition. |
| $\mathrm{t}_{\text {transition }}$ | Delay time between the $50 \%$ and $90 \%$ points of the digital inputs and the switch ON condition when switching from one address state to another. |
| topen | OFF time measured between the $80 \%$ point of both switches when switching from one address state to another. |
| $\mathrm{V}_{\text {INL }}$ | Maximum input voltage for Logic 0 . |
| $\mathrm{V}_{\text {INH }}$ | Minimum input voltage for Logic 1. |
| $\mathrm{IINL}^{\text {(linh }}$ ) | Input current of the digital input. |
| ldo | Positive supply current. |
| Iss | Negative supply current. |
| Off Isolation | A measure of unwanted signal coupling through an OFF channel. |
| Charge Injection | A measure of the glitch impulse transferred from the digital input to the analog output during switching. |
| Bandwidth | The frequency at which the output is attenuated by 3 dBs . |
| On Response | The frequency response of the "ON" switch. |
| THD + N | The ratio of the harmonic amplitude plus noise of the signal to the fundamental. |

## TYPICAL PERFORMANCE CHARACTERISTICS



Figure 4. On Resistance as a Function of VD(VS) for Single Supply


Figure 5. On Resistance as a Function of VD(VS) for Dual Supply


Figure 6. On Resistance as a Function of VD(VS) for Different Temperatures, Single Supply

Figure 7. On Resistance as a Function of VD(VS) for Different Temperatures, Single Supply


Figure 8. On Resistance as a Function of VD(VS) for Different Temperatures, Dual Supply


Figure 9. Leakage Currents as a Function of $V_{D}\left(V_{S}\right)$


Figure 10. Leakage Currents as a function of Temperature


Figure 11. Supply Currents vs. Input Switching Frequency


Figure 12. Charge Injection vs. Source Voltage


Figure 13. TON/TOFF Times vs. Temperature)


Figure 14. Off Isolation vs. Frequency


Figure 15. Crosstalk vs. Frequency


Figure 16. On Response vs. Frequency


Figure 17. THD $+N$ vs. Frequency

## TEST CIRCUITS



Figure 18. Test Circuit 1. On Resistance


Figure 19. Test Circuit 2. I (OFF)


Figure 20. Test Circuit 3. ID (OFF)


Figure 21. Test Circuit 4. ID (ON)


Figure 22. Test Circuit 5. Switching Time of Multiplexer, $t_{\text {TRANSITION }}$


Figure 23. Test Circuit 6. Break-Before-Make Delay, topen

## Preliminary Technical Data



Figure 24. Test Circuit 7. Enable Delay, toN (EN), toff (EN)


Figure 25. Test Circuit 8. Charge Injection


OFF ISOLATION - 20 LOG $V_{\text {OUT }} / V_{\text {IN }}$
Figure 26. Test Circuit 9. OFF Isolation


Figure 27. Test Circuit 10. Channel-to-Channel Crosstalk

## OUTLINE DIMENSIONS



Figure 28. 16-Lead Thin Shrink Small Outline Package [TSSOP] (RU-16)


Figure 29. 16-Lead Lead Frame Chip Scale Package [LFCSP]
$4 \mathrm{~mm} \times 4 \mathrm{~mm}$ (CP-16)
Dimensions shown in inches and (millimeters)

| ORDERING GUIDE |  |  |  |
| :---: | :---: | :---: | :---: |
| Model | Temperature Range | Description | Package Option |
| ADG1408YRU | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | Thin Shrink Small Outline Package (TSSOP) | RU-16 |
| ADG1409YRU | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | Thin Shrink Small Outline Package (TSSOP) | RU-16 |
| ADG1409YCP | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | Thin Shrink Small Outline Package (TSSOP) | CP-16 |
| ADG1409YCP | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | Thin Shrink Small Outline Package (TSSOP) | CP-16 |

Preliminary Technical Data $\quad$ ADG1408/ADG1409

NOTES

## NOTES


[^0]:    ${ }^{1}$ Temperature ranges are as follows: B Version: $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$; Y Version: $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$.
    ${ }^{2}$ Guaranteed by design, not subject to production test.

